Seat No.: Enrolment No			
	GU	JARAT TECHNOLOGICAL UNIVERS	SITY
	BE	- SEMESTER-III(New) • EXAMINATION - WINTE	R 2016
Subject	Code:	2133903 E	Date:06/01/2017
•		:Synthesis of Nanomaterials-I	
•		-	Fotal Marks: 70
Instruction			
		pt all questions.	
		suitable assumptions wherever necessary.	
3.	Figure	es to the right indicate full marks.	MADIZO
			MARKS
Q. 1	1	Short Questions	14
	1	Define 3-D nanostructure.	
	2	Write full form of PVD.	
	3	Draw the structure of 2-D nanomaterial.	
	4	What is the top-down approach?	
	5	Define 1-D Nanomaterials.	
	6	Write examples of 0-D nanomaterial.	
	7	Define nanocrystalline ceramics.	
	8	Define Bottom –up approach.	
	9	What is Nanolayer?	
	10	Write a full form of SWCNT.	
	11	Define quantum confinement effect.	
	12	Give the name of the technique of bottom approach.	
	13	Define the semiconductor nanomaterials.	
•		Define Nanomagnets.	02
Q.2	2 (a)		e 03
	(b)	ratio. Explain Diamond CVD	04
	(D) (C)	Explain blanond CVD Explain safety of Nanomaterials.	04 07
	(C)	OR	07
	(c)	Explain storage issue of Nanomaterials.	07
Q		Give the mechanism of electroplating.	03
~ "	(b)	Explain the tin plating technique.	04
	(c) (c)	Explain solid-gas reaction.	07
	(0)	OR	
Q.3	3 (a)	Explain decomposition.	03
C	(b)	Explain quantum confinement effect on Nano materials.	04
	(c)	Classify Nanomaterial on the basis of shape and size.	07
Q.4		Give the classification of CVD.	03
	(b)	Give the difference between nanomaterial and traditional	al 04
		material.	
	(c)	Explain Nanoscale effect on chemical properties of	of 07
		materials.	
		OR	
Q.4		Discus the top-down approach in detail.	03
	(b)	Write in brief CVD for metal nitride.	04
	(c)	Explain CVD for Semiconductor and metal Oxides.	07
Q.:		Write in brief bottom-up approach.	03
	(b)	Discus preparation of Nano system.	04
	(c)	Explain solid state reaction.	07

OR

Q.5	(a)	Discus dehydration reaction.	03
	(b)	Explain Metal CVD	04
	(c)	Explain the synthesis method for a top-down approach.	07
